







SN54AHCT04, SN74AHCT04

SCLS232R - OCTOBER 1995 - REVISED FEBRUARY 2024

SNx4AHCT04 Hex Inverters

1 Features

- Inputs are TTL-voltage compatible
- Latch-up performance exceeds 250mA per JESD 17
- On products compliant to MIL-PRF-38535, all parameters are tested unless otherwise noted. On all other products, production processing does not necessarily include testing of all parameters.

2 Applications

- Servers
- **Network switches**
- Telecom infrastructures
- Tests and measurements

3 Description

The SNx4AHCT04 devices contain six independent inverters. These devices perform the Boolean function $Y = \overline{A}$

Package Information

_	aonago imormat	
PART NUMBER	PACKAGE ⁽¹⁾	BODY SIZE (NOM)(2)
	J (CDIP, 14)	19.56mm × 6.67mm
SN54AHCT04	W (CFP, 14)	13.09mm × 6.92mm
	FK (LCCC, 20)	8.89mm × 8.89mm
	N (PDIP , 14)	19.3mm × 6.35mm
	D (SOIC, 14)	8.65mm × 3.91mm
	NS (SOP, 14)	10.30mm × 5.30mm
SN74AHCT04	DB (SSOP, 14)	6.20mm × 5.30mm
3N74A11C104	PW (TSSOP, 14)	5.00mm × 4.40mm
	DGV (TVSOP, 14)	3.60mm × 4.40mm
	RGY (VQFN, 14)	3.50mm × 3.50mm
	BQA (WQFN, 14)	3.00mm × 2.50mm

- For more information, see Section 11.
- The body size (length × width) is a nominal value and does not include pins.

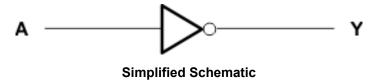




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4 Pin Configuration and Functions

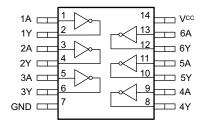


Figure 4-1. SN54AHCT04 J or W Package, 14-Pin (Top View)
SN74AHCT04 D, DB, DGV, N, NS, or PW Package, 14-Pin (Top View)

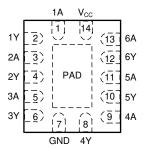


Figure 4-2. SN74AHCT04 RGY or BQA Package, 14-Pin (Top View)

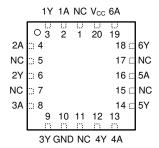


Figure 4-3. SN54AHCT04 FK Package, 20-Pin (Top View)

Table 4-1. Pin Functions

	P	IN				
	SN74AHC	CT04	SN5	54AHCT04	TYPE ⁽¹⁾	DESCRIPTION
NAME	D, DB, DGV, N, NS, PW	RGY, BQA	J, W	FK		DECORAL FIGH
1A	1	1	1	2	I	1A Input
1Y	2	2	2	3	0	1Y Output
2A	3	3	3	4	I	2A Input
2Y	4	4	4	6	0	2Y Output
3A	5	5	5	8	I	3A Input
3Y	6	6	6	9	0	3Y Output
4A	9	9	9	13	I	4A Input
4Y	8	8	8	12	0	4Y Output
5A	11	11	11	16	ı	5A Input
5Y	10	10	10	14	1	5Y Output
6A	13	13	13	19	1	6A Input
6Y	12	12	12	18	0	6Y Output
GND	7	7	7	10	_	Ground Pin
NC	_	_	_	1, 5, 7, 11, 15, 17	_	No Connection
V _{CC}	14	14	14	20	_	Power Pin
Thermal Pad	_	PAD	_	_	_	Thermal Pad

⁽¹⁾ I = input, O = output



5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	7	V
VI	Input voltage range ⁽²⁾		-0.5	7	V
Vo	Output voltage range ⁽²⁾		-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V _I < 0		-20	mA
I _{OK}	Output clamp current	$V_O < 0$ or $V_O > V_{CC}$		±20	mA
Io	Continuous output current	$V_O = 0$ to V_{CC}		±25	mA
	Continuous current through V_{CC} or GND			±50	mA
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

5.2 ESD Ratings

			Value	UNIT
		Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	±2000	
V _(ESD)	Electrostatic discharge	Charged device model (CDM), per ANSI/ESDA/JEDEC JS-002, all pins ⁽²⁾	±1000	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(1)

	5 1 5 1	SN54AHC	SN54AHCT04		T04	UNIT	
		MIN	MAX	MIN	MAX	UNII	
V _{CC}	Supply voltage	4.5	5.5	4.5	5.5	V	
V _{IH}	High-level input voltage	2		2		V	
V _{IL}	Low-level input voltage		0.8	0	0.8	V	
VI	Input voltage	0	5.5	0	5.5	V	
Vo	Output voltage	0	V _{CC}	0	V _{CC}	V	
I _{OH}	High-level output current		-8		-8	mA	
I _{OL}	Low-level output current		8		8	mA	
Δt/Δν	Input transition rise or fall rate		20		20	ns/V	
T _A	Operating free-air temperature	-55	125	-40	125	°C	

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI Application Report, Implications of Slow or Floating CMOS Inputs, (SCBA004).

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⁽²⁾ The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



5.4 Thermal Information

					SN74A	HCT04				
	THERMAL METRIC(1)	D	DB	DGV	N	NS	PW	RGY	BQA	UNIT
				<u> </u>	14 F	PINS		<u> </u>	<u> </u>	
R _{θJA}	Junction-to-ambient thermal resistance	124.5	113.1	138.7	61.1	120.9	147.7	63.7	88.3	
R _{0JC(top)}	Junction-to-case (top) thermal resistance	78.8	65.6	60.6	48.0	78.2	77.4	77.6	90.9	
R _{θJB}	Junction-to-board thermal resistance	81	60.4	71.8	41.0	81.6	90.9	39.7	56.8	°C/W
Ψлт	Junction-to-top characterization parameter	37	25.5	10.6	32.4	42.8	27.2	5.7	9.9	- C/VV
ΨЈВ	Junction-to-board characterization parameter	80.6	59.9	71.1	40.9	81.1	90.2	39.9	56.7	
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	N/A	N/A	N/A	19.9	33.4	

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, (SPRA953).

5.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	v	T,	λ = 25°C		SN54AH	ICT04	SN74AH	CT04	UNIT
PARAIVIETER	TEST CONDITIONS	V _{cc}	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
V	I _{OH} = –50 μA	4.5 V	4.4	4.5		4.4		4.4		V
V _{OH}	I _{OH} = –8 mA	4.5 V	3.94			3.8		3.8		V
V	I _{OL} = 50 μA	4.5 V			0.1		0.1		0.1	V
V _{OL}	I _{OL} = 8 mA	4.5 V			0.36		0.44		0.44	
II	V _I = 5.5 V or GND	0 V to 5.5 V		•	±0.1		±1 ⁽¹⁾		±1	μΑ
Icc	V _I = V _{CC} or GND, I _O = 0	5.5 V			2		20		20	μΑ
ΔI _{CC} ⁽²⁾	One input at 3.4 V, Other inputs at V _{CC} or GND	5.5 V			1.35		1.5		1.5	mA
Ci	V _I = V _{CC} or GND	5 V		4	10				10	pF

⁽¹⁾ On products compliant to MIL-PRF-38535, this parameter is not production tested at $V_{CC} = 0 \text{ V}$.

5.6 Switching Characteristics, $V_{CC} = 5 V \pm 0.5 V$

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 6-1)

PARAMETER	FROM	ТО	LOAD	T	A = 25°C		SN54Al	HCT04	SN74AH	ICT04	UNIT	
	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX		
t _{PLH}	A	Y	Y C _L = 15 pF		4.7 ⁽¹⁾	6.7 ⁽¹⁾	1 ⁽¹⁾	7.5 ⁽¹⁾	1	7.5	no	
t _{PHL}	А			CL = 13 pr	OL = 13 pi	- Ο[- 13 βί		4.7 ⁽¹⁾	6.7 ⁽¹⁾	1 ⁽¹⁾	7.5 ⁽¹⁾	1
t _{PLH}	۸	V	C = 50 pE		5.5	7.7	1	8.5	1	8.5	no	
t _{PHL}	А		C _L = 50 pF		5.5	7.7	1	8.5	1	8.5	ns	

(1) On products compliant to MIL-PRF-38535, this parameter is not production tested.

⁽²⁾ This is the increase in supply current for each input at one of the specified TTL voltage levels, rather than 0 V or V_{CC}.



5.7 Noise Characteristics

 $V_{CC} = 5 \text{ V}, C_L = 50 \text{ pF}, T_A = 25^{\circ}C^{(1)}$

	PARAMETER		SN74AHCT04			
	PARAMETER	MIN	TYP	MAX	UNIT	
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}		0.8		V	
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}		-0.8		V	
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}		4.7		V	
V _{IH(D)}	High-level dynamic input voltage	2			V	
$V_{IL(D)}$	Low-level dynamic input voltage			0.8	V	

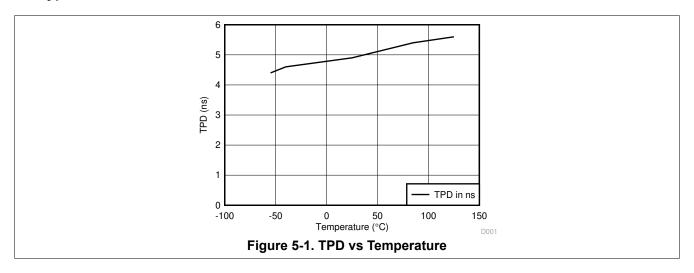
⁽¹⁾ Characteristics are for surface-mount packages only.

5.8 Operating Characteristics

 V_{CC} = 5 V, T_A = 25°C

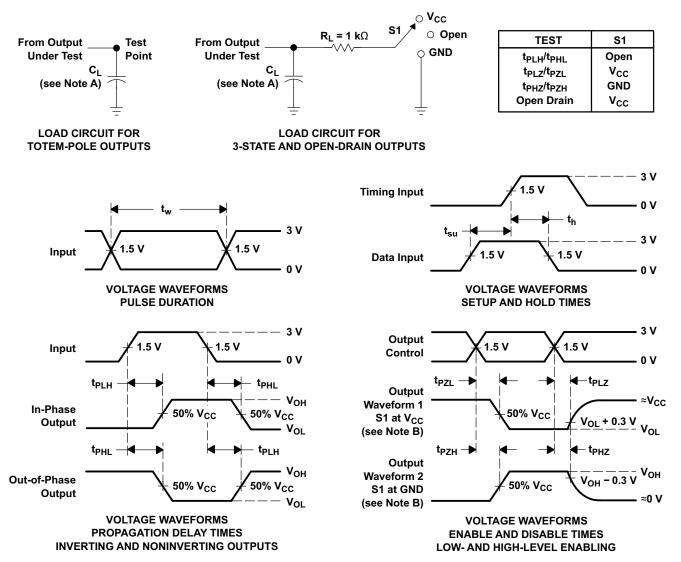
	PARAMETER		CONDITIONS	TYP	UNIT
C_{pd}	Power dissipation capacitance	No load,	f = 1 MHz	14	pF

5.9 Typical Characteristics





6 Parameter Measurement Information



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_O = 50 Ω , $t_r \leq$ 3 ns, $t_f \leq$ 3 ns.
- D. The outputs are measured one at a time with one input transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

Figure 6-1. Load Circuit and Voltage Waveforms



7 Detailed Description

7.1 Overview

The SNx4AHCT04 devices contain six independent inverters. These devices have TTL input levels that allow up translation from 3.3 V to 5 V.

7.2 Functional Block Diagram



7.3 Feature Description

- V_{CC} is optimized at 5 V
- Allows up voltage translation from 3.3 V to 5 V
 - Inputs Accept V_{IH} levels of 2 V
- Slow edge rates minimize output ringing
- Inputs are TTL-voltage compatible

7.4 Device Functional Modes

Table 7-1. Function Table (Each Inverter)

INPUT A	OUTPUT Y
Н	L
L	Н

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8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

The SNx4AHCT04 is a low-drive CMOS device that can be used for a multitude of inverting type applications where output ringing is a concern. The low drive and slow edge rates will minimize overshoot and undershoot on the outputs. The input switching levels have been lowered to accommodate TTL inputs of 0.8-V V_{IL} and 2-V V_{IH} . This feature makes it ideal for translating up from 3.3 V to 5 V. Figure 8-1 and Figure 8-2 show this type of translation.

8.2 Typical Application

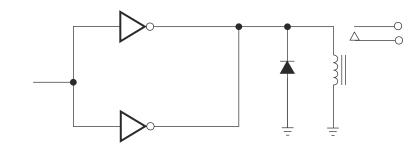


Figure 8-1. Driving Relays

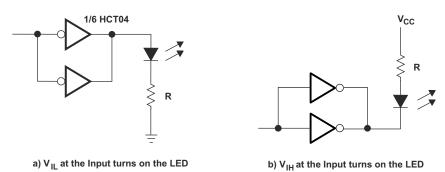


Figure 8-2. Driving LEDs

8.2.1 Design Requirements

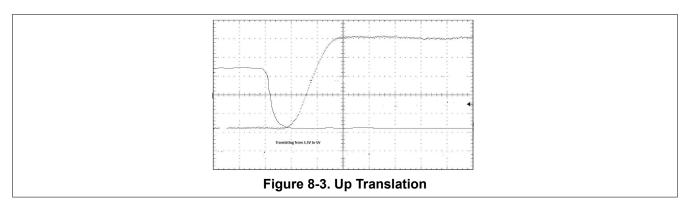
This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads, so routing and load conditions should be considered to prevent ringing.

8.2.2 Detailed Design Procedure

- 1. Recommended input conditions
 - Rise time and fall time specs: See (Δt/ΔV) in the Recommended Operating Conditions table.
 - Specified High and low levels: See (V_{IH} and V_{IL}) in the Recommended Operating Conditions table.
- 2. Recommend output conditions
 - · Load currents should not exceed 25 mA per output and 50 mA total for the part
 - Outputs should not be pulled above V_{CC}



8.2.3 Application Curves



8.3 Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the *Recommended Operating Conditions* table.

Each V_{CC} pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1 μ F is recommended. If there are multiple V_{CC} pins, 0.01 μ F or 0.022 μ F is recommended for each power pin. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. A 0.1 μ F and 1 μ F are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

8.4 Layout

8.4.1 Layout Guidelines

When using multiple bit logic devices inputs should not ever float.

In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. #none# shows the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC} ; whichever makes more sense or is more convenient. It is generally acceptable to float outputs unless the part is a transceiver. If the transceiver has an output enable pin, it will disable the outputs section of the part when asserted. This will not disable the input section of the IOs, so they cannot float when disabled.

8.4.2 Layout Example

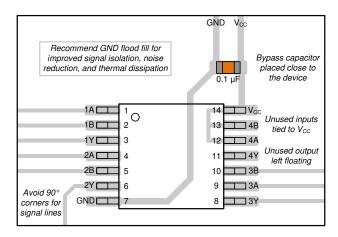


Figure 8-4. Example Layout for the SN74AHCT04

9 Device and Documentation Support

9.1 Documentation Support (Analog)

9.1.1 Related Documentation

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 9-1. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
SN54AHCT04	Click here	Click here	Click here	Click here	Click here
SN74AHCT04	Click here	Click here	Click here	Click here	Click here

9.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

9.4 Trademarks

TI E2E[™] is a trademark of Texas Instruments.

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9.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision Q (October 2023) to Revision R (February 2024)

Page

Changes from Revision P (May 2023) to Revision Q (October 2023)

Page



11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



www.ti.com 2-Dec-2024

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9680401Q2A	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9680401Q2A SNJ54AHCT 04FK	Samples
5962-9680401QCA	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9680401QC A SNJ54AHCT04J	Samples
5962-9680401QDA	ACTIVE	CFP	W	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9680401QD A SNJ54AHCT04W	Samples
SN74AHCT04BQAR	ACTIVE	WQFN	BQA	14	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHCT04	Samples
SN74AHCT04D	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	-40 to 125	AHCT04	
SN74AHCT04DBR	ACTIVE	SSOP	DB	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB04	Samples
SN74AHCT04DGVR	ACTIVE	TVSOP	DGV	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB04	Samples
SN74AHCT04DR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHCT04	Samples
SN74AHCT04N	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 125	SN74AHCT04N	Samples
SN74AHCT04NSR	ACTIVE	SOP	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHCT04	Samples
SN74AHCT04PW	OBSOLETE	TSSOP	PW	14		TBD	Call TI	Call TI	-40 to 125	HB04	
SN74AHCT04PWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	HB04	Samples
SN74AHCT04RGYR	ACTIVE	VQFN	RGY	14	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	HB04	Samples
SN74AHCT04RGYRG4	ACTIVE	VQFN	RGY	14	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	HB04	Samples
SNJ54AHCT04FK	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9680401Q2A SNJ54AHCT 04FK	Samples
SNJ54AHCT04J	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9680401QC A SNJ54AHCT04J	Samples

PACKAGE OPTION ADDENDUM

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Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SNJ54AHCT04W	ACTIVE	CFP	W	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9680401QD A SNJ54AHCT04W	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN54AHCT04, SN74AHCT04:

PACKAGE OPTION ADDENDUM

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Catalog : SN74AHCT04

• Military : SN54AHCT04

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

• Military - QML certified for Military and Defense Applications



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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AHCT04BQAR	WQFN	BQA	14	3000	180.0	12.4	2.8	3.3	1.1	4.0	12.0	Q1
SN74AHCT04DBR	SSOP	DB	14	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
SN74AHCT04DGVR	TVSOP	DGV	14	2000	330.0	12.4	6.8	4.0	1.6	8.0	12.0	Q1
SN74AHCT04DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74AHCT04DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74AHCT04NSR	SOP	NS	14	2000	330.0	16.4	8.45	10.55	2.5	12.0	16.2	Q1
SN74AHCT04NSR	SOP	NS	14	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
SN74AHCT04PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74AHCT04PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74AHCT04PWR	TSSOP	PW	14	2000	330.0	12.4	6.85	5.45	1.6	8.0	12.0	Q1
SN74AHCT04RGYR	VQFN	RGY	14	3000	330.0	12.4	3.75	3.75	1.15	8.0	12.0	Q1



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*All dimensions are nominal

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AHCT04BQAR	WQFN	BQA	14	3000	210.0	185.0	35.0
SN74AHCT04DBR	SSOP	DB	14	2000	356.0	356.0	35.0
SN74AHCT04DGVR	TVSOP	DGV	14	2000	356.0	356.0	35.0
SN74AHCT04DR	SOIC	D	14	2500	356.0	356.0	35.0
SN74AHCT04DR	SOIC	D	14	2500	353.0	353.0	32.0
SN74AHCT04NSR	SOP	NS	14	2000	353.0	353.0	32.0
SN74AHCT04NSR	SOP	NS	14	2000	367.0	367.0	38.0
SN74AHCT04PWR	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74AHCT04PWR	TSSOP	PW	14	2000	353.0	353.0	32.0
SN74AHCT04PWR	TSSOP	PW	14	2000	366.0	364.0	50.0
SN74AHCT04RGYR	VQFN	RGY	14	3000	356.0	356.0	35.0

PACKAGE MATERIALS INFORMATION

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TUBE



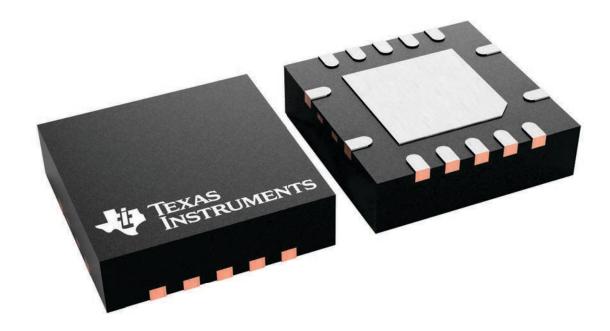
*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
5962-9680401Q2A	FK	LCCC	20	55	506.98	12.06	2030	NA
5962-9680401QDA	W	CFP	14	25	506.98	26.16	6220	NA
SN74AHCT04N	N	PDIP	14	25	506	13.97	11230	4.32
SN74AHCT04N	N	PDIP	14	25	506	13.97	11230	4.32
SNJ54AHCT04FK	FK	LCCC	20	55	506.98	12.06	2030	NA
SNJ54AHCT04W	W	CFP	14	25	506.98	26.16	6220	NA

3.5 x 3.5, 0.5 mm pitch

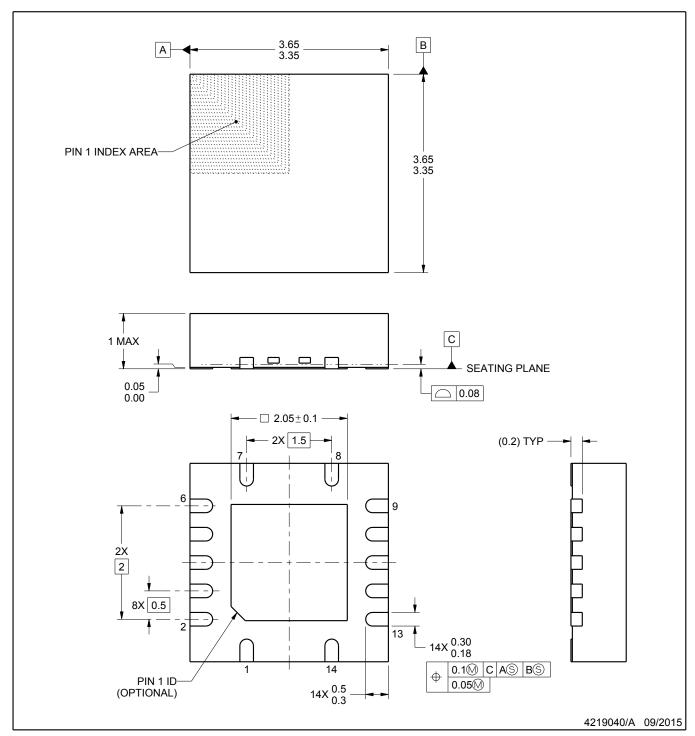
PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





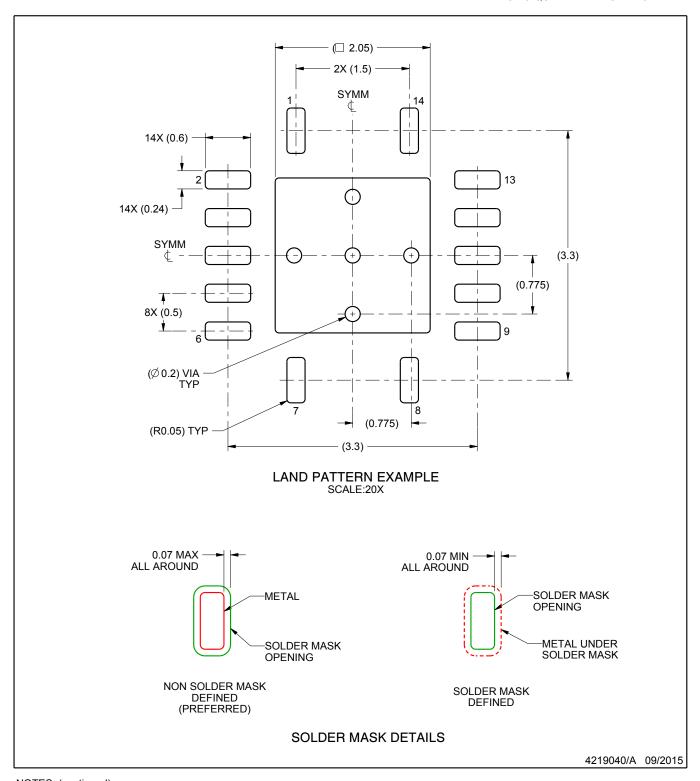
PLASTIC QUAD FLATPACK - NO LEAD



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- This drawing is subject to change without notice.
 The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC QUAD FLATPACK - NO LEAD

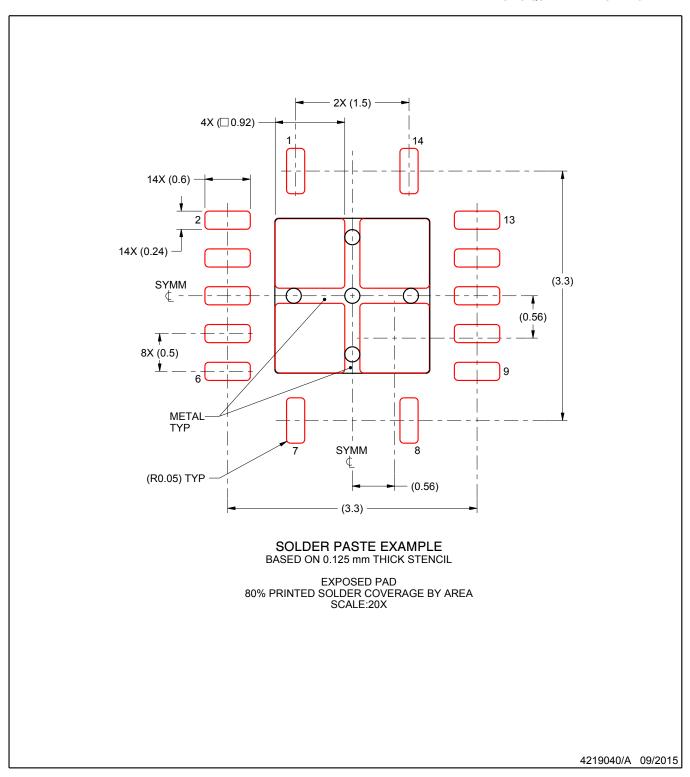


NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.





SMALL OUTLINE INTEGRATED CIRCUIT



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
- 5. Reference JEDEC registration MS-012, variation AB.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



2.5 x 3, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



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PLASTIC QUAD FLAT PACK-NO LEAD



- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.



PLASTIC QUAD FLAT PACK-NO LEAD



NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



PLASTIC QUAD FLAT PACK-NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



W (R-GDFP-F14)

CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only.
- E. Falls within MIL STD 1835 GDFP1-F14







- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
 4. Reference JEDEC registration MO-150.





NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



CERAMIC DUAL IN LINE PACKAGE



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4040083-5/G





CERAMIC DUAL IN LINE PACKAGE



- 1. All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This package is hermitically sealed with a ceramic lid using glass frit.
- His package is remitted by sealed with a ceramic its using glass mit.
 Index point is provided on cap for terminal identification only and on press ceramic glass frit seal only.
 Falls within MIL-STD-1835 and GDIP1-T14.



CERAMIC DUAL IN LINE PACKAGE



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.







- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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